Diode Semiconductor Device - Page 1 of 1



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#### **Inclosure Material:**

Glass

**Overall Length:** 

0.300 inches

# Terminal Length:

1.000 inches

# **Overall Diameter:**

0.130 inches

### **Mounting Method:**

Terminal

### **Features Provided:**

Hermetically sealed case

### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

3.3 regulator voltage

# **Current Rating Per Characteristic:**

116.00 milliamperes repetitive peak forward current

# **Power Rating Per Characteristic:**

400.0 milliwatts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

# **Special Features:**

Gnuclear hardness critical item; no drawing to determine if isc code 1 item should also be nuclear hardness. Can't change criticality code to reflect nuclear hardness; junction pattern arrangement: pin

# **Precious Material And Location:**

Leads gold

#### **Precious Material:**

Gold

# Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

2 uninsulated wire lead

#### **Specification Data:**

81349-mil-s-19500/435 government specification

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

# Fiig: